SKN 71

Stud Diode

Rectifier Diode

SKN 71

SKR 71

Features

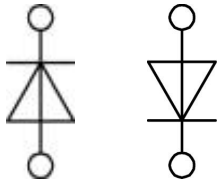
- Reverse voltages up to 1600 V
- Hermetic metal case with glass insulator
- Threaded stud ISO M8 and also 1/4-28 UNF
- SKN: anode to stud, SKR: cathode to stud

Typical Applications

- All-purpose mean power rectifier diodes
- Cooling via heatsinks
- Non-controllable and half-controllable rectifiers
- Free-wheeling diodes
- Recommended snubber network: RC: 0,1 µF, 100 Ω (P_R = 2 W), R_P = 80 kΩ (P_R = 6 W)

V_{RSM} V	V_{RRM} V	I_{FRMS} = 150 A (maximum value for continuous operation) I_{FAV} = 70 A (sin. 180; T_c = 125 °C)	
400	400	SKN 71/04	SKR 71/04
800	800	SKN 71/08	SKR 71/08
1200	1200	SKN 71/12	SKR 71/12
1400	1400	SKN 71/14	SKR 71/14
1600	1600	SKN 71/16	SKR 71/16

Symbol	Conditions	Values	Units
I_{FAV}	sin. 180; T_c = 100 °C	95	A
I_D	K 1,1; T_a = 45 °C; B2 / B6	112 / 159	A
	K 1,1F; T_a = 35 °C; B2 / B6	174 / 246	A
I_{FSM}	T_{vj} = 25 °C; 10 ms	1150	A
	T_{vj} = 180 °C; 10 ms	1000	A
i²t	T_{vj} = 25 °C; 8,3 ... 10 ms	6600	A²s
	T_{vj} = 180 °C; 8,3 ... 10 ms	5000	A²s
V_F	T_{vj} = 25 °C; I_F = 200 A	max. 1,5	V
$V_{(TO)}$	T_{vj} = 180 °C	max. 0,85	V
r_T	T_{vj} = 180 °C	max. 3	mΩ
I_{RD}	T_{vj} = 180 °C; V_{RD} = V_{RRM}	max. 10	mA
Q_{rr}	T_{vj} = 160 °C; - di_F/dt = 10 A/µs	70	µC
$R_{th(j-c)}$		0,55	K/W
$R_{th(c-s)}$		0,2	K/W
T_{vj}		- 40 ... + 180	°C
T_{stg}		- 55 ... + 180	°C
V_{isol}		-	V~
M_s	to heatsink	4	Nm
a		5 * 9,81	m/s²
m	approx.	18	g
Case		E 11	



SKN SKR

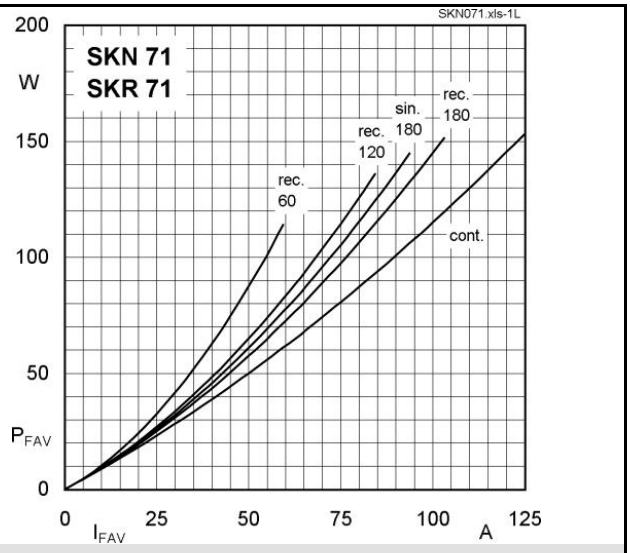


Fig. 1L Power dissipation vs. forward current

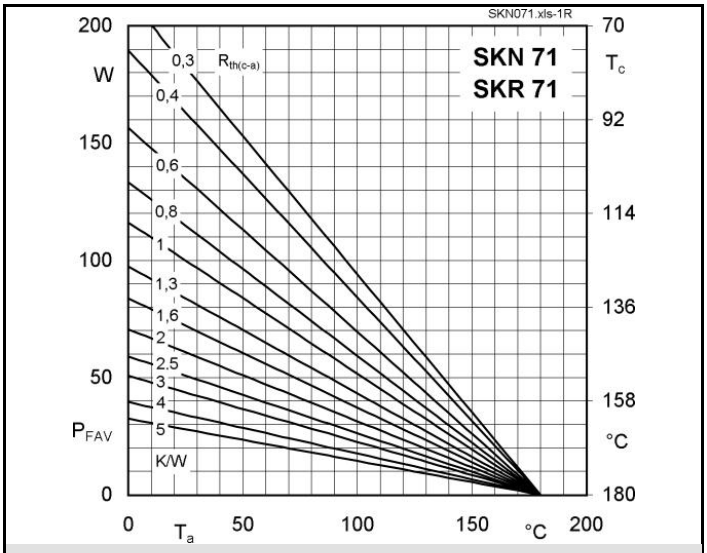


Fig. 1R Power dissipation vs. ambient temperature

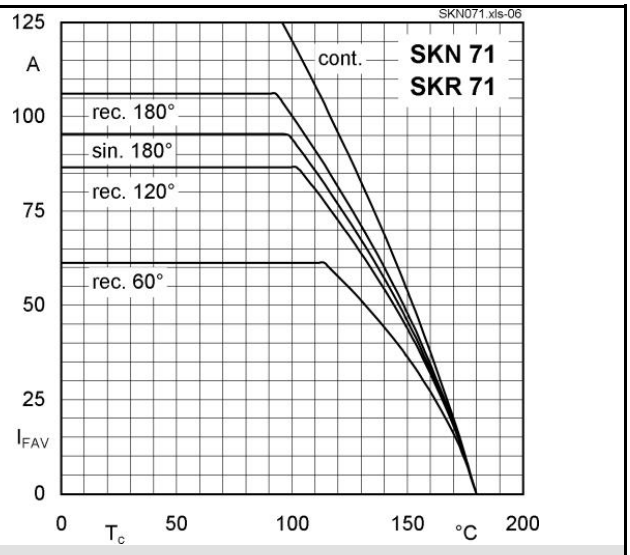


Fig. 2 Forward current vs. case temperature

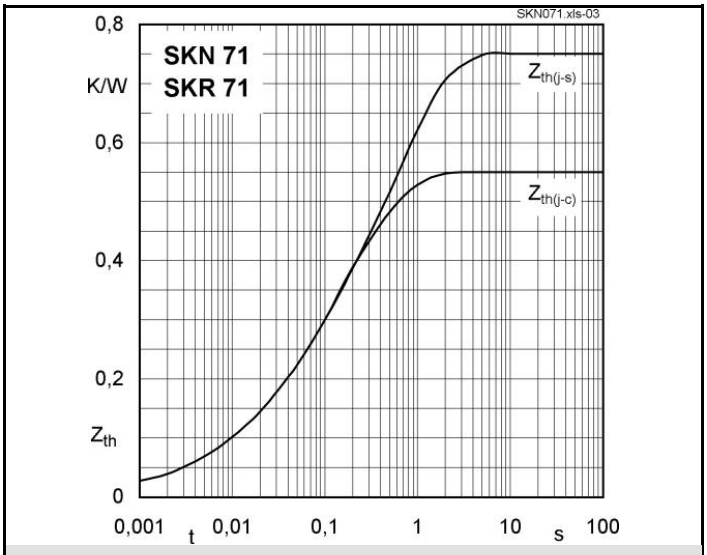


Fig. 4 Transient thermal impedance vs. time

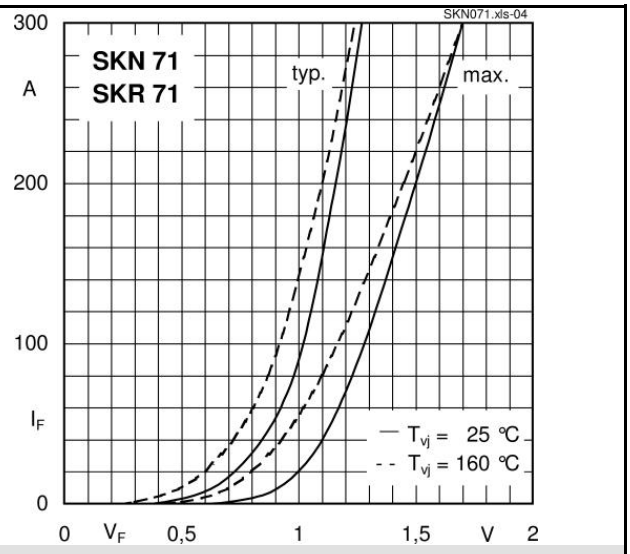


Fig. 5 Forward characteristics

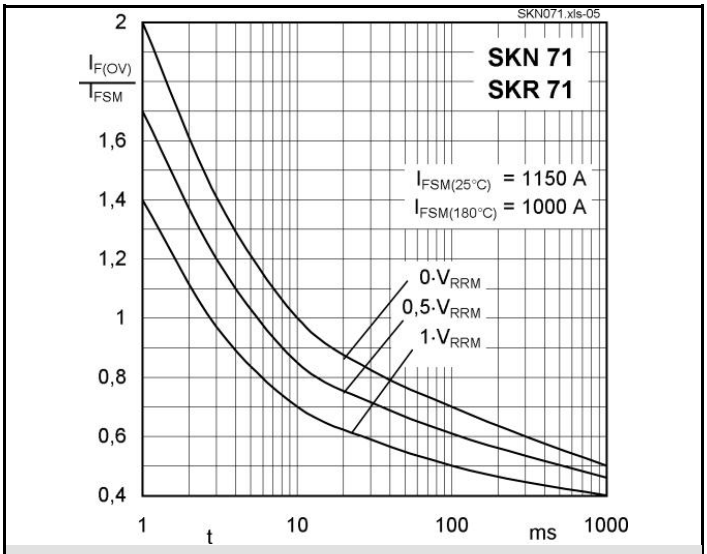
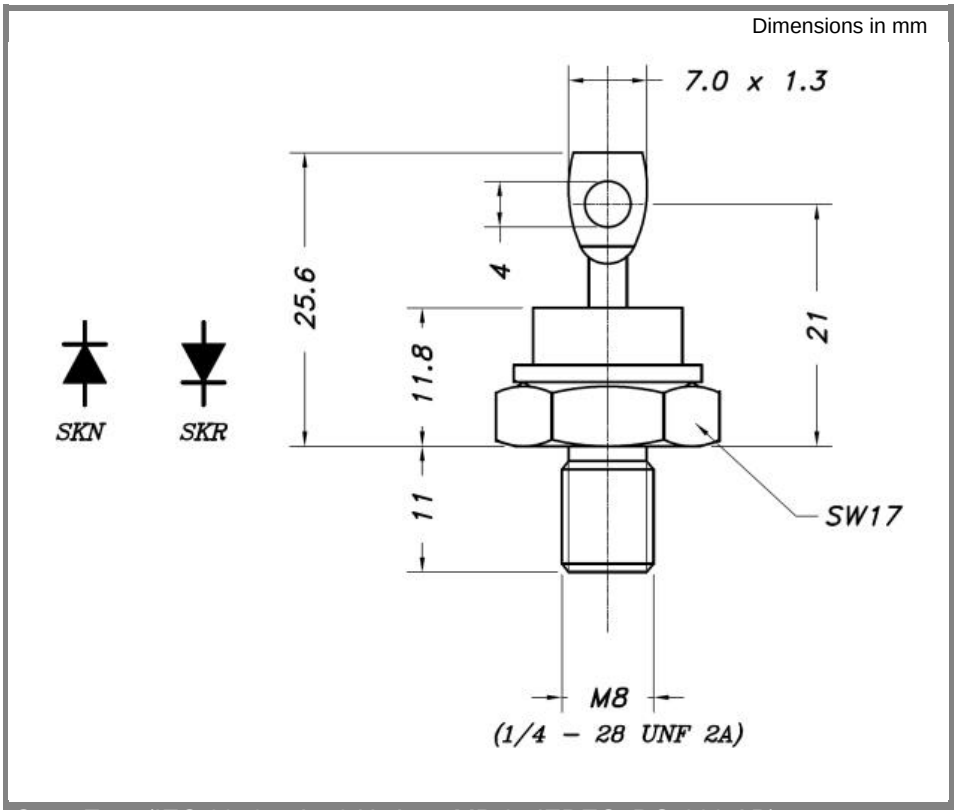


Fig. 6 Surge overload current vs. time



Case E 11 (IEC 60191: A 16 U, A 17 MB 2; JEDEC: DO-203 AB)

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